Ferm i liquid param eters in 2D with spin-orbit interaction

D.S. Saraga and Daniel Loss

Department of Physics and Astronomy, University of Basel, Klingelbergstrasse 82, CH-4056 Basel, Switzerland
(Dated: 9th January 2022)

We derive analytical expressions for the quasiparticle lifetime , the electron ass m, and the G reen's function renormalization factor Z for a 2D Fermi liquid with electron-electron interaction in the presence of the Rashba spin-orbit interaction. We not that the modications are independent of the Rashba band index, and occur in second order of the spin-orbit coupling. In the derivation of these results, we also discuss the screening of the Coulomb interaction, as well as the susceptibility and the self-energy in small.

PACS: 71.10.Ca, 73.21.-b, 71.18.+ y

I. INTRODUCTION

The lifetime of quasiparticle excitations determined by electron-electron collisions is a crucial quantity of the Ferm i liquid theory of interacting electron system s. In particular, the quasi-particle lifetime for a twodim ensional electron gas as found e.g. in sem iconductor heterostructures has been now studied in great detail^{2,3}. has been traditionally of importance for phenom ena that are based on coherent transport such as for exam ple conductance uctuations, weak-localization, or the Aharonov-Bohm e ect4, this quantity is also im portant for the current strive towards quantum information processing in the solid state, which requires the coherent propagation of e.g. entangled electrons. In this respect, as well as in the emerging eld of spintronics, the spin degree of freedom is increasingly being investigated⁵.

The e ect of spin-orbit (s-o) interaction in lowdim ensional system s has consequently become an important issue, and has uncovered new functionalities such as the spin-based transistor⁶, spin in jection⁷ and the electric manipulation of spin in non-magnetic semiconductors, and has also led to new physics with the spin-Hall e ect9 15. The consideration of s-o interaction in the fram ework of Ferm i liquid theory is therefore desireable. Existing work has investigated electronic transport and plasm on excitations 16,17, Friedel-like oscillations in the screened potential 18 , and the modication of the s-o coupling due to electron-electron interactions 19. W hile the spin relaxation and decoherence rates have been widely studied in such system s²⁰, the relaxation rate of the quasiparticle itself has not, to our know ledge, been studied so far.

An important contribution to the electron band comes from the renormalization of the electron band mass by electron-electron interactions. Simple expressions form in 2D appear in early works addressing the g-factor²¹ and the spin susceptibility²², and were followed by numerical studies²³. Some recent work addressed non-analytic corrections²⁴, the temperature dependence²⁵, and the elects of impurity scattering²⁶. A nother important parameter of Fermi liquid theory is the renormalization factor Z of the Green's function¹. This quantity measures the quasiparticle spectral weight, and gives the

size of discontinuity of the zero tem perature Ferm i occupation factor n () at the Ferm i surface. For a clean 2D EG without impurities and so interaction, it has rst been studied for short-range potentials $^{\!2^{\!7}}$, while the realistic case with Coulomb interaction has been studied numerically $^{\!28}$ and analytically $^{\!29,30}$. Recent related work used Ferm i liquid theory to study plasm ons contributions to the elective mass in valley-degenerate system s $^{\!41}$, spin resonance and the spin-Hall conductivity $^{\!42}$, as well as screening and plasm on modes $^{\!43}$

This work presents an analytical study of the e ect of s-o interaction on the quasiparticle lifetim e, the Z -factor, and the e ective mass m in a two dimensional Fermiliauid, taking the speci c case of the Rashba interaction 31. We consider the long-range Coulomb interaction, and work within the random phase approximation (RPA) valid for small rs 1 (high densities). For the lifetime, we nd that the spin-orbit contribution appears in second order of the s-o coupling , and contains a logarithm ic term sim ilar to the standard lifetim e2, where the excitation energy is replaced by the Rashba splitting 2 $k_F = \sim$. A sim ilar result is found for the e ective mass, with a m odi cation of the form $^2 \log$. For the Z -factor, we nd a quadratic term without logarithm ic enhancem ent. In all these cases the modications are independent of the Rashba band index denoting the two directions of the eigenspinors of the Rashba Hamiltonian. We also discuss brie v the screening of the Coulomb interaction, and derive expressions both the real and im aginary parts of the susceptibility , com plem enting the expressions found in Refs. 16,17,18. We also give general arguments showing that the self-energy and, consequently, the Ferm i liquid param eters, cannot have any modication linear in Throughout this work we consider a clean system at zero tem perature.

II. 2D FERMILIQUID WITH RASHBA S-O IN TERACTION

A. Rashba eigenstates

We consider an electron in a 2D Fermi liquid in the presence of the Rashba spin-orbit interaction restricted

to the z = 0 plane, described by the H am iltonian H = p^2 =2m + H $_{so}$ w ith 31

$$H_{so} = - (p_x^y p_y^x):$$
 (1)

Expressed in the z-spin basis j i, the eigenstates are

$$\dot{x}; i = \frac{1}{P - 2} \quad i e^{i (k)} \quad \dot{x};$$
(2)

with the polar angle $(k) = \ \ (k; 0 x)$ and the momentum eigenstates ki. The index = de nes the two Rashba bands. We de ne the s-o strength

$$= \frac{k_R}{k_F} = \frac{k_F = 2E_F}{2E_F} = \frac{E_R}{2E_F}$$
 (3)

from the Rashba m om entum

$$k_R = m = \sim;$$
 (4)

the Rashba energy E $_R$ = m $^2\!=\!\!\sim^2$, and the Fermienergy E $_F$ = k_F^2 =2m . We de ne the excitation energy by $_k$ = E $_k$ E_F , with the dispersion relations for the two branches E $_k$ = k^2 + 2 $k_R\,k$ =2m . Setting $_k$ = 0 yields the two Fermim om enta

$$k = k \text{ with } = k_F \frac{p}{1 + 2}$$
: (5)

Note that both k and $\,$ will replace k_F in a number of the expressions valid without s-o interaction . We dene the unperturbed M atsubara 1 G reen's function

$$G (k; ik_n) = \frac{1}{ik_n}$$
 (6)

corresponding to the Rashba eigenstates (2) without electron-electron interaction. We have introduced the ferm ionic M atsubara frequency k_n = (2n + 1) $k_B \; T \; ; n \; 2 \; N$.

B. Renorm alization due to the electron-electron interaction.

W ithin Fermi liquid theory, the presence of electronelectron interaction modiles the retarded G reen's function¹

$$G^{R}(k;) = G(k; ik_{n}! + i0^{t}) = \frac{1}{k^{R}(k;)}$$

$$\frac{Z}{k^{H} + i(\sim = 2) (k)}$$
(7)

describing a quasiparticle belonging to the Rashba band with a momentum $\,k$. To derive the expression above, one has expanded for small frequencies and small excitation energies $_k$ above the Fermi surface, i.e. E_F , $0 < _k$ E_F , k k k. In this procedure, one rst shifts the Fermi momentum $\,k$ via the requirement

 $_{k}$ + Re R (k;0) = 0. The lifetime of the quasiparticle, (k) = 1= (k), is given via

$$(k) = \frac{2}{\pi} \text{Im} \, (k; k);$$
 (8)

where the self-energy contains the e ect of the C oulom b electron-electron interaction.

The Green's function acquires a renormalized weight

$$Z = \frac{1}{1 - A}; \tag{9}$$

with
$$A := \frac{\theta}{\theta} \mathbb{R} e^{-\mathbb{R}} (k; = 0)$$
 (10)

which gives the size of the jum p in the Ferm i occupation factor n () at the Ferm i surface.

The e ective mass enters in the renormalized excitation energy $_k = k^2 + 2 \ k_R \ k \ k_F^2 = 2m$, and is dened by

$$\frac{m}{m} = \frac{1}{Z} \frac{1}{1+B};$$
 (11)

with B :=
$$\frac{m}{\theta k} \mathbb{R} e^{-R} (k = k; 0)$$
: (12)

As the excitation energy must vanish at the Ferm i surface, one has $_k\ =\ 0$ and thus k_F is also shifted with k . Note that it is , not k , that enters in the factor m= appearing in B .

In order to study the modi cations introduced by the Rashba interaction, we rst present here the results found without s-o interaction. The inverse lifetime reads 2,3,32

$$_{0}(k) = \frac{\frac{2}{k}}{E_{F}} \log \frac{k}{E_{F}} + O(r_{s})$$
 : (13)

The r_s -factor is de ned here 33 as $r_s=k_{T\,F}=2k_F=m\,e_0^2=\sim^2\frac{1}{2}$ n, where n is the electronic sheet density (in the absence of s-o interaction), and $k_{T\,F}$ is the T hom as-Ferm i screening m om entum . The two important characteristics of (13) are: (i) $_0$! 0 when $_k$! 0, corresponding to long-lived quasiparticle excitations near the Ferm i surface; (ii) the vanishing of is slowed down by a logarithm ic factor.

The e ective m ass contains a term $$r_{\!s} \log r_{\!s}$, and is given by <math display="inline">^{21}$

$$\frac{m_0}{m}$$
 $1 = \frac{r_s}{m} [\log r_s + 2 \log 2 + 0 (r_s)]$: (14)

The deviation of the renorm alization weight Z from 1 is linear with $r_{\rm S}$, and reads²⁹

$$Z_0 = \frac{r_s}{1 + \frac{r_s}{2} + 0} i$$
 (15)

Taking a GaAs 2DEG with 34 n = 4 16 m 2 , one has $r_s = 0.614$, $Z_0 = 0.50$, and $m_0 = m$ 1 = 0.16. An InAs 2DEG with e.g. 35 n = 10 16 m 2 , m = 0.03m $_{e}$ and $r_s = 0.18$ has the parameters $Z_0 = 0.83$ and $m_0 = m$ 1 = 0.019.

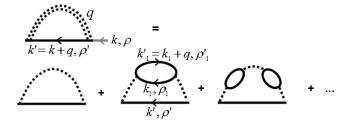


Figure 1: The diagram atic representation of the self-energy (k) (23) in RPA. The full lines denote the electron G reen's functions (6), the dashed lines the Coulomb interaction, the circles are the susceptibility bubble diagram (18), and the double dashed line is the screened Coulomb interaction (17). The Rashba bands are denoted by the 's, and yield the overlap factor F $^{\circ}$ (19).

C. Screening of the Coulom b interaction

In order to build a Ferm i liquid theory including the s-o interaction, we must consider the matrix elements of the bare 2D C oulom b interaction V_C (q) = 2 e_0^2 =q~ in the R ashba eigenstates basis. These matrix elements involve the overlap

$$F = \frac{1}{4} \stackrel{h}{1} + {}_{1} \stackrel{0}{1} e^{i(\stackrel{0}{1} \quad 1)} \stackrel{ih}{1} + {}_{2} \stackrel{0}{2} e^{i(\stackrel{0}{2} \quad 2)} \stackrel{i}{}$$
 (16)

of the eigenspinors (2), which depends on the directions f_{1} ; $_{2}$; $_{1}^{0}$; $_{2}^{0}$ g of the scattered states and on their band indices f_{1} ; $_{2}$; $_{1}^{0}$; $_{2}^{0}$ g. In RPA 1 , we not the screened C oulom b potential

$$V(q;!) = \frac{V_C(q)}{(q;!)}F;$$
 (17)

where " = 1 V_C is the dielectric function. In M atsubara form alism 1 , the susceptibility is given by the bubble diagram

where $k^0 = \frac{1}{12}k + q$, $ik_n^0 = ik_n + iq_n$, $= \setminus (k; k^0)$, $(2)^2 = k$! dk and $q_n = 2n$ $k_B T$ is a bosonic M atsubara frequency. The corresponding diagrams are represented in Fig. 1. The last factor

$$F^{0} = \frac{1 + {}^{0} \cos}{2}$$
 (19)

is the overlap F $\,$ for states w ith opposite m om enta. A fler sum m ing over ik_n and perform ing the analytical continuation $iq_n~!~!+i0^+$, one ~ nds

$$\mathbb{R}e \quad (q;!) = \begin{array}{c} X \\ \frac{n(k) \quad n(k^{0})}{! + k} & k^{0} \\ \end{array}$$

Im
$$(q;!) = X$$
 $(! + {}_{k} {}_{k^{\circ}} {}_{\circ})$ $[n ({}_{k}) n ({}_{k^{\circ}} {}_{\circ})]F^{0};$ (21)

which is the standard form with the additional F 0 factors. As we consider zero temperature, the Ferm i occupation factor reads n() = (). Note that the elect of the spin-orbit interaction manifests itself in the energies $_{\rm k}$, while the factors F 0 alone just describe a change of the spin basis. In particular, such a basis change could also be considered in the absence of s-o interaction. For instance, the scattering cross-section for two electrons 36 , given in Born approximation by

$$= \frac{1}{2 k} \frac{m}{\kappa^2} V (q)^2; \qquad (22)$$

vanishes for di erent Rashba bands in case of forward scattering (e.g. $_{1}^{0}$ = $_{1}$, k_{1}^{0} = k_{1}), while it vanishes for same bands in the case of backscattering (k_{1}^{0} = k_{1}). This only rejects the fact that the real spin is conserved by the Coulomb interaction. For forward scattering the spin basis does not change, so that the band index must be the same. The opposite happens for backscattering, where the spin basis is inverted and the band index must be changed in order to preserve the real spin. This is the same reason why the two conjugate states of the K ramers doublet belong to the same Rashba band $_{1}^{37}$.

D . Self-energy

The self-energy is the central quantity that determ ines the other Ferm i-liquid param eters. In lowest order in the screened intraction (RPA), it is given by 1

$$(k; ik_n) = k_B T X X G \circ (k^0; ik_n^0) V \circ (q; iq_n);$$

$$(23)$$

and is represented in Fig. 1. Here the screened potential (17) $V^0 = F^0V_C =$ involves F^0 because of momentum conservation. At zero temperature the inverse lifetime 1 = 0 is given by

$$(k; k) = \frac{2}{x} \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) \times (k \cdot k) = \frac{2}{x} \times (k \cdot k) \times (k \cdot$$

with ! = $k k^0 W$ e now introduce the param eters

$$x^{0} = \frac{q}{2k} \text{ and } y^{0} = \frac{m!}{q};$$
 (25)

which are relevant for the susceptibility entering in V (see Sec. III). We consider small excitation energies above the Ferm i surface

$$0 < k' \frac{m}{m} \quad E_F$$
 , $= k \quad k \quad k$: (26)

U sing ! = k^2 $k^0 + 2k_R$ (k^0) = 2m , we see that the functions in (24) yield

$$0 < y^{0} < y^{0}$$
 $\frac{\text{m axf } ; k_{R} g}{q}$: (27)

Note that a priori, neither x^0 nor y^0 have to be small; however, one can check numerically that the dominant contributions to (24) come from forward scattering, i.e. for

q. k,
$$x^{0}$$
 1: (28)

For the lifetime, one can also assume y^0 1. For these reasons we shall calculate the susceptibility in the lim it x^0 1, before taking y^0 1.

III. SUSCEPT IB IL IT Y

The susceptibility (or, equivalently, the dielectric function = 1 \ Y \) for a 2D EG w ith s-o interaction has been partially studied in Refs. 16,17,18 in the smallq k_F lim it. Expressions for the imaginary part of in the lim it q k_R ; k_F have been given in Refs. 16,17 in the context of transport. Ref. 18 , which addressed non-analytic contributions to the real part of , only gives expressions for q! 0 for the interband case (di erent Rashba bands), while the intraband case is studied in the q! $2k_F$ case. Therefore, it is desireable to complement these studies by deriving expressions for both Re and Im in the q! 0 lim it.

We rst write the 2D susceptibility $_{0}$ without Rashba interaction 38 . Introducing the parameters

$$x = \frac{q}{2k_F} \text{ and } y = \frac{m!}{qk_F};$$
 (29)

the susceptibility reads in the Matsubara formalism (iyn ! y + i0 $^{+}$)

$$_{0}(x; iy_{n}) = \frac{m}{-1} \frac{1}{x} R s(z)^{p} \frac{1}{z^{2}} i;$$
 (30)

where $z = x + iy_n$, $z = x iy_n$, R[f(z)] = [f(z) + f(z)] = 2, and s(z) = sgn[Re(z)] arising from the choice of the (1;0] branch cut for z.

We now derive the susceptibility (20)-(21) in the lim it of small q; k_R k. We rst write (q;!) = $p \frac{0}{1+2\cos'} (q=k) + (q=k)^2$ in small q to get the energy dierence

$$_{k}$$
 $_{k^{\circ}} \circ ' \frac{k}{m} k_{R} () \frac{q}{m} (k + {}^{0}k_{R}) \cos' : (31)$

W e also expand the Ferm i function

$$n(_{k^{0}})$$
 $n(_{k})$ $(_{k}$ $_{k^{0}})$ $(_{k})$; (32)

which selects k = k, and the spinor overlap

$$\frac{1 - \cos}{2} = \frac{1}{2} \quad 1 \quad \frac{k + q\cos'}{k^0} \quad ' \quad \frac{1}{2} \quad \frac{1}{2} \quad \frac{q}{2k} \sin'$$
(33)

These expansions are valid for $q_i k_R$ k.

A. Intraband contributions (
$$^{0} =$$
)

We rst consider transitions within a given Rashba band. We can neglect $(q=k)^2$ in the spinor overlap, and integrate over ' and k. We nd

For the imaginary part, (! + $_k$ $_{k^0}$ $_0$) selects ' = A rccos(y0) if \dot{y} 0j< 1, and we get

Im ; =
$$\frac{m}{2} \frac{y^0}{1} \frac{y^0}{1} (1 + y^0) 1 = \frac{k_R}{1}$$
 ; (35)

which agrees with Eq. (35) of Ref. 16 . Sum m ing over , we see that the intraband contributions to are independent of the band index .

B. Interband contributions ($^{0} =$)

For transitions between two di erent Rashba bands, it is necessary to distinguish between two cases.

(a)
$$k_R$$
 q k.We nd

$$\mathbb{R}e \;\; ; \;\; = \;\; \frac{m}{2} x^2 \;\; \frac{1}{2} + \;\; \dot{y}\dot{j} \;\; \frac{p}{y^2 \;\; 1} \quad \dot{\hat{y}} \quad (\dot{y}\dot{j} \;\; 1) \;\; ;$$

Im , =
$$\frac{m}{2} x^2 y^p \frac{1}{1 + y^2} (1 + y^2);$$
 (37)

where we have also expanded in y^0 , y.

(b) $q = k_R ; k . W e get$

Re ; =
$$\frac{1}{16} \frac{q^2}{!} \log \frac{=k_R + 4E_F =! 1}{=k_R + 4E_F =! + 1}$$

, $\frac{m}{4} x^2 \frac{1}{1 + m! = 2 k_R k_F}$; (38)

where we have expanded in small k_R in the second equality. Note the unusal term m $!=k_R\,k_F$. Setting !=0 and sum ming over yields the static result (24) of Ref. in the limit $k_B\,T$! 0. For the imaginary part we nd

X Im ; =
$$\frac{m}{8} \frac{x}{y}$$
 (! < $j! j < !_+$); (39)

with ! = 2 ($k_{\rm k}$) $k_{\rm R}$ =m . This expression (39) agrees with Eq. (37) of Ref. and Eq. (10) of Ref. , which are relevant for the optical conductivity. One can neglect this contribution when calculating the lifetime, as in this case q; $k_{\rm F}$ =m) x=y y. The other interband contributions are negligible compared to the intrabands ones, as they are smaller by the factor x² 1.

C. Total susceptibility

Adding the two intrabands branches, we not for the susceptibility

$$\mathbb{R}e \quad (q! \quad 0;!) = \quad \frac{m}{1} \quad 1 \quad \frac{\dot{y}^{0}\dot{j}}{\sqrt{2} \quad 1} \quad (\dot{y}^{0}\dot{j} \quad 1) \quad (40)$$

Im
$$(q! 0;!) = \frac{m}{2} \frac{y^0}{1} (1 \dot{y}^0)$$
 (41)

which corresponds to the case without Rashba interaction (30) in the $\lim \pm x \cdot 1 = 0$, where one replaces y by the new parameter y^0 . We can now take the $\lim \pm 0$ small energy, $y^0 = 1$, and we nally not the susceptibility in the presence of Rashba s-o interaction

$$(q! 0;! ! 0) = \frac{m}{} (1 + iy^{0});$$
 (42)

which we shall use in the calculations of the Ferm i-liquid parameters below. Note that in general Eqs. (20) and (21) yields that (q; !) = (q; !). In particular, Re and Im are respectively even and odd in y in the lim it q = 0, as seen in our expressions above.

IV. SUSCEPT IB ILITY AND SELF-ENERGY FOR SMALL

In this section we show on general grounds that the expansion of $\$ and $\$ in $\$ sm $\$ all $\$ have no term $\$ linear in

A. Susceptibility

The susceptibility has only a second-order contribution from the s-o interaction,

$$= _{0} + O (^{2});$$
 (43)

because is an even function of $k_R=m=\sim$. This can be seen by expanding around = 0 via the function $h\left(\begin{smallmatrix}k&;&k^0&0\end{smallmatrix}\right)$:= $[h\left(\begin{smallmatrix}k&\end{smallmatrix}\right) & n\left(\begin{smallmatrix}k^0&0\end{smallmatrix}\right)]$ = (i! $_n$ + $_k$ $_{k^0&0}$). We use d $_k$ =dk $_R$ = k=m and $_k$ = k^2 =2m $_E$, and nd

$$(q;i!_n) = \frac{1}{2} X X (1 + {}^{0}\cos)$$

$$\frac{X}{j!} \frac{1}{m} \frac{k_R}{m} \xrightarrow{j} k \frac{e}{e_k} + {}^{0}k^{0} \frac{e}{e_{k^{0}}} \xrightarrow{j} h(_{k};_{k^{0}});(44)$$

and notice that the sum s over ; 0 cancel for odd powers j. This result is consistent with Eqs. (34)-(39), where the term s linear in k_R vanish after sum ming over ; 0.

B. Self-energy

We rst perform the sum over the Rashba band index 0 in the self-energy (23)

$$(k; ik_n) = k_B T H (q; ik_n^0) \frac{V_C (q)}{\P (q; iq_n)};$$
 (45)

w here

$$H (q; ik_n^0) = \frac{+ (k + q \cos)}{2 (k^0)^2};$$
 (46)

and $= ik_n^0 k^0$. We expand in small and nd

H (q;
$$ik_n^0$$
) ' $\frac{1}{0}$ + 0 (²) $\frac{1}{2}$ + $\frac{1}{3}$: (47)

where $_0 = (! 0)$. (We recall that k, being close to k, depends on .)

The integrations of the $\,$ rst and third terms do not yield any logarithm ic term in $\,$ because their divergence at $_0$ = 0 is odd with respect to q. On the contrary, the term O (2)= 2_0 brings logarithm ic contributions, as will be seen in the lifetime and the elective mass below. Because "= 1 $\,$ Vc $\,$ has also no term linear in , we not that the modication of the self-energy due to the s-o interaction can only appear in second order.

V. LIFETIME

In this section we calculate the lifetime as given by Eq.(8).W e rst de ne the Thomas-Fermi m om entum

$$k_{TF} = \frac{2m e_0^2}{r} = 2r_s k_F;$$
 (48)

and assum e that the sm all q contributions dom inate such that m V (q)= = $k_{T\,F}$ =q 1 (this is justified in GaAs where k_s ′ 12 k_F). We nd

Im
$$V^{0}(q;!) = \frac{V_{C}^{2}(q)}{(1 + k_{TF} = q)^{2} + (k_{TF} = q)^{2}y^{0}}$$
 $\frac{m}{}y^{0} F^{0}$
' $\frac{-y^{0}F^{0}}{m}$: (49)

Note that it is F 0 {and not F 0 { that appears here with V 2 , because the screening involves only V, without F 0 . Writing (k) = $_0$; $_0$ (k) and changing variables $_q$! $_k$, we have

$$; \circ (k) = \frac{1}{8 \sim m} \sum_{k=0}^{Z_k} dk^0 k^0 (_{k^0} \circ _{k^0}) I \circ ;$$
 (50)

w here

$$I_{0} = \frac{Z_{2}}{0} d \frac{1 + {}^{0}\cos}{q(k^{0};)};$$
 (51)

 $\overset{\text{H}}{P} \frac{\text{ere } k = k + k_R \text{ (}}{k^2 + k^{12} - 2kk^{12} \cos} \quad \overset{\text{0}}{\text{)}}, \quad = \text{ (k; k^0), and q(k^0;) = }$ band contributions.

We nd

$$I = \frac{2}{kk^{0}jk k^{0}j} (k + k^{0})^{2}K (z) (k k^{0})^{2}E (z);$$
(52)

k $^\prime$ k . A fter perform ing the k integration and expanding in small $\,$ k up to second order, we nally get

; (k) =
$$\frac{2}{2 \text{ rm}} \log \frac{1}{8k} + \frac{1}{2}$$

' $\frac{2}{2 \text{ rm}} \log \frac{1}{8k_F} + \frac{1}{2} + \frac{1}{$

W e also expanded in small $k_{R} \,\,$ $\,\,$ $k_{F} \,$ in the second line.

B. Interband case (
$$^{0} =$$
).

We nd

$$I = \frac{2jk}{kk^0} j [K (z) E (z)]:$$
 (54)

W e repeat the same procedure and expand in $\mbox{ ; } k_R = k_F$. We get

;
$$(k) = \frac{2}{2} \ln 1 + \frac{1}{2} \log \frac{0}{4}$$
 : (55)

We now add the two Rashba branches. The term linear in $k_{\rm R}$ vanishes and we nally get for the lifetime including the Rashba s-o interaction

$$(k) = \frac{\frac{2}{2 \text{ m}}}{\frac{2}{4 \text{ m}}} \log \frac{1}{8k_F} = \frac{1}{2} \frac{2 \log \frac{1}{4}}{\frac{2}{2 \log \frac{1}{4}}}$$

$$= \frac{\frac{2}{k}}{4 \text{ m}} \log \frac{k}{16E_F} = \frac{1}{2} \frac{E_R}{E_F} \log \frac{E_R}{8E_F};$$

valid up to = (~m) 0 ; 2 . We recognize in the rst term the standard lifetime for a 2D Ferm i liquid w ithout R ashba interaction 2,3 , w ith the logarithm ic enhancement log(= 1 F) log(1 E F).

The modi cation to the lifetime due to the spin-orbit interaction also contains a logarithm ic factor $\log (k_R = \! k_F) - \log (\ _R = \! E_F)$ involving the Rashba splitting at the Ferm i surface, $_R = 2 \ k_F = \!\!\!\!\sim$. We note that for typical GaAs 2D EGs this modi cation is rather weak, because of the factor $= k_R = \!\!\!\!\! k_F$ 1, and therefore does not modify signicantly the usual term valid without so interaction.

We now derive the expression for the renormalization factor Z (9). We give some details of the calculation, in order to show the cancellation of the log ${\tt g}$ term, as well as to introduce integrations that will also be useful for the calculation of the excise mass. Our starting point is the real part of the self-energy entering in Eq. (10). At $k_B\,T=0$, one can replace the sum over the M atsubara frequencies appearing in (23) by an integral along the imaginary axis, $k_B\,T_{iq_h}\,f\,(iq_h)$! (1=2) duf (iu). Thus we need to evaluate

$$A = \frac{e}{e} \mathbb{R} e^{X} \frac{1}{2} \int_{q^{-0}}^{Z_{-1}} du G \circ (k^{0}; ik_{n} + iu) V^{0}(q; iu);$$
(57)

where $k^0 = k + q$, k = k and one sets = 0 after taking the derivative. While the analytical continuation $ik_n ! + i0$, must be taken after the integration, one can reverse this order (i.e., make the analytical continuation rst), i

$$A = A^{\text{res}} \quad \frac{X}{q^{\circ}} \quad \frac{\mathbb{R}e}{q^{\circ}} \quad \frac{\mathbb{R}}{q^{\circ}} \quad \frac{\mathbb{R}$$

provided that one compensates for the contributions of the poles of G by adding the \residue" term

$$A^{\text{res}} = Re_{q^{0}}^{X} \underbrace{\theta}_{q^{0}} [(k_{0}^{0} \circ) (k_{0}^{0} \circ)]$$

$$V^{0}(q; k_{0}^{0} \circ)$$

$$= X \qquad \qquad = 0$$

$$(k_{0}^{0} \circ) V^{0}(q; 0) : \qquad (59)$$

We have used in Eq. (58) the fact that the integrated function is even in u. For the remaining term, we notice that $(G \circ (k^0; + iu)) = i(Q_1 G \circ (k^0; iu))$ when = 0 and integrate by parts over u. The boundary term with u! 1 vanishes, while the term with u! 0_+ gives

$$A_{\text{boundary}}^{(u! \ 0_{+})} = Re i \frac{1}{}^{X} G \circ (k^{0}; i0_{+}) V^{0}(q; i0_{+})$$

$$= X G \circ (k^{0}; i0_{+}) V^{0}(q; i0_{+})$$

$$= X G \circ (k^{0}; i0_{+}) V^{0}(q; i0_{+}) G \circ (i0_{+}) G \circ (i0_{+})$$

where we have used $\mbox{Im } G \circ (k^0; i0_+) = (k^\circ \circ).$ We see that this boundary term cancel with the residue term $\mbox{A}^{\rm res}$. This is important, as these terms actually contain a term that is logarithmic in $r_{\rm s}$ [see Eq. (70) in the calculation of m below]. Thus we have

$$A = \operatorname{Im} \frac{1}{2} X \operatorname{Im} \frac{1}{2} \operatorname{duG} \circ (k^{0}; \operatorname{in}) \frac{\theta}{\theta u} V^{0}(q; \operatorname{in})$$

$$= \frac{r^{0}}{2^{2}} X \operatorname{Im} \frac{z_{1}}{\theta u} \operatorname{dy}^{0} \operatorname{d} \operatorname{dx}^{0} f(x^{0}; y^{0};) : (62)$$

We have de ned r^{00} = m e_0^2 =k \sim = $k_{T\,F}$ =2k , y^{00} = m u=qk , and x^{00} = q=2k . The integrand is

$$f(x^{0}; y^{0};) = \frac{F^{0}}{iy^{0}} \frac{1}{x^{0} n^{2}} \frac{\theta^{n}}{\theta^{0}};$$
 (63)

where F $^{0}(x^{0};)$ = 1=2 + $^{0}(1 + 2x^{0}\cos)$ =2' is the overlap of the eigenspinors, ' $(x^{0};)$ = $\frac{1}{1 + 4x^{0}\cos + 4x^{0}}$ = k^{0} =k, $(x^{0};)$ = $\cos + x^{0}$ + (0 ' 1) 0 =2 x^{0} is the dimensionless energy $_{k^{0}}$, and 0 = k_{R} =k is a modiled s-o strength.

We now consider the RPA lim it of high density, which corresponds to small $r^{00}-1$. In this case, the dominant contribution comes from the intraband case ($^{0}=-$) with $x^{00}-1$, where we can use the approximations F^{0} , 1+0 (x^{00}), x^{00} , x^{00} , $x^{00}+r^{0}$ a (y^{0}) + 0 (x^{00}), r^{0} (r^{0}), and we have dended a (r^{0}) = 1 r^{0} ye r^{0} and r^{0} = m u=q = r^{0} =(1+ r^{0}). Dening r^{0} = m e $_{0}^{2}$ = r^{0} =(1+ r^{0}), we have

A '
$$\frac{r^0}{2^2} \lim_{X \to 0} \frac{Z_1}{dy^0} \frac{\theta}{\theta y^0} a(y^0) \frac{Z_2}{\theta y^0} d \frac{1}{iy^0} \frac{1}{\cos x}$$

$$= \frac{r^0}{2^2} \lim_{X \to 0} \frac{dy^0}{\theta y^0} \frac{\theta}{\theta y^0} \frac{r^0}{x^0 + ra(y^0)}$$

$$= \frac{r^0}{2^2} \frac{1}{\theta y^0} \frac{1}{(y^2 + 1)^2} \frac{1}{a(y^0)}$$

$$= \frac{r^0}{2^2} \frac{1}{\theta y^0} \frac{1}{(y^2 + 1)^2} \frac{1}{a(y^0)}$$
(64)

The remaining terms (in particular, the contribution from the interband transition with $^0=$) are neglected as they are 0 $~\rm r^{1/2}$. We now use

$$r^0 = r_s + 1 + 2 + 1 = 2 \cdot r_s + 1 + \frac{1}{2} \cdot r_s$$
 (65)

and the renormalization factor reads

$$Z = 1 \frac{r_{s}}{2} + \frac{1}{2} + \frac{1}{2} = 1 \frac{\frac{1}{2}}{2}$$

$$= 1 \frac{r_{s}}{2} + \frac{1}{2} + \frac{\frac{E_{R}}{E_{F}}}{2} : (66)$$

This result is valid up to 0 (r_s^2 ; r_s ³), so that the m odication from the result (15) without so disappears in the case $\frac{P}{r_s}$ 1. Similarly to the inverse lifetime, we see that the Z-factor is independent of the Rashba band index , and that its modication appears only in second order in the strength of the so interaction. This modication can be traced back to the small shift of the Fermi surface due to the so interaction. Without so interaction (= 0), Eq. (66) corresponds to the result presented in Refs. $\frac{29}{r^3}$.

VII. EFFECTIVE MASS

The calculation for the e ective mass (11) is similar in spirit to the Z factor calculation, but is more involved.

We start with

$$B = \frac{m}{e^{\frac{\theta}{2}}} \mathbb{R} e^{\frac{X}{e^{\frac{1}{2}}}} \frac{1}{2} \int_{1}^{Z} du G \circ (k^{0}; ik_{n} + iu) V^{0}(q; iu);$$
(67)

where k ! k after taking the derivative. Again, we rst perform the analytical continuation ik_n ! + i0, by adding a residue term ($_{k^0}$ _0) ($_{k^0}$ _0). Contrary to the case for Z , this residue term identically vanishes once we take = 0. Hence we have

$$B = \mathbb{R} e^{\frac{m}{2}} X \frac{1}{2} du \frac{e}{e^{k}} G \circ (k^{0}; iu) V^{0}(q; iu) ;$$

$$k = k$$
(68)

which we integrate by parts. W ith the change of variables $q \ ! \ k^0$, the boundary term reads

$$B_{\text{boundary}}^{(u!\ 0+)} = \frac{m}{k} X_{(k^{\circ}\ \circ)} V^{0}(q; 0) \frac{\theta_{k^{\circ}\ \circ}}{\theta k}$$

$$= \frac{r^{0}}{8} X_{0} \frac{k^{\circ}}{k} \frac{Z^{2}}{\theta k} d \frac{\cos}{x^{0}(k^{\circ}) + r^{0}} (1 + e^{0} \cos k^{\circ});$$
(69)

where x^{00} $_{0}$ () = (1=2k) $\frac{q}{k^{2}{_{0}}}$ $2k_{0}k$ $cos + k^{2}$ and we recall that r^{0} = m e_{0}^{2} = \sim . W e consider the case r_{s} ; 1 and nally get

$$B_{\text{boundary}}^{(u!\ 0_+)} = \frac{r_s}{2} \log \frac{r_s}{2} + 2 + \frac{4}{3} \frac{2}{2} \log + 0 (r_s; ^2) :$$
(70)

The remaining integrated term of the integration by parts in (68) contains two terms. The rst one reads

$$B_{int}^{(1)} = \operatorname{Im} \frac{m}{m} X^{X} \overset{Z}{=} 1 \operatorname{duG} \circ (k^{0}; iu) \frac{e}{eu} V^{0}(q; iu) \frac{e_{k^{0}} \circ e}{ek} :$$
(71)

We see that the integrand is identical to the expression (61) appearing in the calculation made for Z , apart from the factor ($_{k^0}$ = ($_{k^0}$) = ($_{k^m}$) (

$$B_{int}^{(1)} = \frac{r^0}{1 + \frac{1}{2}} : (72)$$

The second term reads

$$B_{int}^{(2)} = \mathbb{R} e^{\frac{m}{2}} X^{\frac{Z_1}{2}} duG \circ (k^0; in) \frac{V_C(q)}{(q; in)} \frac{e^{F^0}}{e^k}; (73)$$

where $@F^0=@k = ^0q^2 \sin^2 = 2k^{(8)}$: The analysis of this integral is rather demanding, as no approximation is accurate and only a numerical solution seems possible. However, a careful examination of the dierent terms shows that there is no logarithmic contribution | in particular, the small x contributions are suppressed by the overall x^3 dependence. We can now use the general argument about the self-energy (see Sec. IV B), which

states that no term linear in can be present in the e ective mass. This implies that this integral B $_{\rm int}^{(2)}$ compensates for the linear term appearing in (70), which is conmed by numerical integrations.

Finally, we obtain the e ective mass (11)

$$\frac{m}{m}$$
 $1 = \frac{r_s}{m}$ $\log r_s + 2$ $\log 2$ $\frac{1}{2}$ $\log 2$; (74)

where we used the expression (66) for Z . We recognize in the rst three terms the unperturbed result (14). The modi cation induced by the s-o interaction has the form $^2\log$, similarly to the lifetime, Eq. (66) We see that particles in dierent Rashba spin eigenstates have, to lowest order, the same e ective mass.

VIII. CONCLUSION

We have calculated the main quasiparticle parameters (the inverse quasi-particle lifetime 1= , the renormalization factor Z , and the electroner mass m) due to the Coulomb electronelectron interaction in a 2D Fermiliquid with Rashba interaction. The modications due to so interaction are found to be independent of the Rashba band index , and to appear only in second order in the so strength $E_R = E_F \quad \text{with some logarithmic enhancement for the lifetime and the elective mass.}$

The spin-orbit constant being rather small in typical semiconductor 2DEGs, these modication will be

very small, around 10 3 . For instance, a GaAs 2DEG with 40 = 0.5 $10^{12}\,\mathrm{eV}\,\mathrm{m}$, n = 4 $1^{10}\,\mathrm{m}^{-2}$ yields k_R = 0.43 m 1 . This gives a rather small = 2.7 10^3 , so that one gets only very small modications Even for an InGaAs 2DEGs with larger s-o coupling and with 35 = 30 $10^{12}\,\mathrm{eV}\,\mathrm{m}$ for n = 10 $1^{10}\,\mathrm{m}^{-2}$, m = 0.03m $_{\mathrm{e}}$ and r_{s} = 0.18, one has a modest = 0.051.

W e note that replacing the R ashba interaction by the D resselhaus interaction H $_{\rm D}$ = ($_{\rm R}$ $_{\rm X}$ + $_{\rm Y}$ $_{\rm Y}$)=~ yields exactly the same results. Indeed, the only dierence lies in the eigenspinors (the phase is decreased by =2), so that their overlap F $^{\rm O}$, Eq.(19), is unchanged and the energies have the same form . N atural extensions of this work are the studies of the e ect of the so interaction on the renormalized g-factor $^{\rm 21}$, the consideration of short-range potential instead of the C oulomb interaction, nite temperatures, and the presence of a perpendicular or parallel magnetic eld as used to measure the mobility and the elective mass or to manipulate electron spins.

A cknow ledgm ents

We thank B.Altshuler, M.Duckheim, J.C.Egues, and S.Erlingsson for useful discussions. We are particularly grateful to S.Chesi for very valuable remarks. This work has been supported by NCCR \N anoscale Science", Swiss NSF, EU-Spintronics, DARPA, ARO, and ONR.

G.D.Mahan, Many-particle physics (Plenum, New York, 1990); H.Bruus and K.Flensberg, Many-Body Quantum Theory in Condensed Matter Physics: An Introduction (Oxford University Press, 2004).

A.V. Chaplik, Sov. Phys. JETP 33, 997 (1971); G. F. Giuliani and J.J. Quinn, Phys. Rev. B 26, 4421 (1982).

J. Zheng and S. Das Sarma, Phys. Rev. B 53, 9964 (1996);
D. Menashe and B. Laikhtman, Phys. Rev. B B54, 11561 (1996);
T. Jungwirth and A. H. MacDonald, Phys. Rev. 53, 7403 (1996);
M. Reizer and J.W. Wilkins, Phys. Rev. B 55, R7363 (1997).

⁴ See e.g.S.W ashburn and R.A.W ebb, Rep.Prog.Phys.55 1311 (1992).

⁵ Sem iconductor Spintronics and Quantum Computation, ed.D.D.Awschalom, D.Loss, and N.Samarth (Springer-Verlag, Berlin, 2002).

⁶ S.D atta and B.D as, Appl.Phys.Lett.56,665 (1990).

A. Voskoboynikov, S.S. Lin, and C.P. Lee, J. Appl. Phys. 87, 387 (2000); T. Koga, J. Nitta, H. Takayanagi, and S. Datta, Phys. Rev. Lett. 88, 126601 (2002); A. A. Kiselev and K.W. Kim, Appl. Phys. Lett. 78, 775 (2001).

 $^{^8}$ Y .K ato, R \pounds .M yers, A \pounds .G ossard, D D .Aw schalom , N ature 427, 50 (2004).

 $^{^9}$ S.M urakam i, N.Nagaosa, and S.C.Zhang, Science 301, 1348 (2003).

 $^{^{10}\,}$ J. Sinova, D. Culcer, Q. Niu, N. A. Sinitsyn, T. Jungwirth,

and A.H.MacDonald, Phys.Rev.Lett.92, 126603 (2004)

 $^{^{11}}$ Y.K.Kato, R.C.Myers, A.C.Gossard, and D.D. Awschalom, Science 306, 1910 (2004).

J.W underlich, B.K aestner, J.Sinova, T.Jungwirth, Phys. Rev. Lett. 94, 047204 (2005).

¹³ J.Schliem ann and D.Loss Phys. Rev. B 69, 165315 (2004).

 $^{^{14}}$ O.Chalaev and D.Loss, cond-m at/0407342.

¹⁵ S.I.Erlingsson, J.Schliem ann, and D.Loss, Phys.Rev.B 71,035319 (2005).

¹⁶ E.G. M ishchenko and B.I. Halperin, Phys. Rev. B 68, 045317 (2003).

¹⁷ L J.M agaril, A W.Chaplik, and M.W.Entin, JETP 92, 153 (2001).

¹⁸ G.H. Chen and M.E. Raikh, Phys. Rev. B 59, 5090 (1999).

¹⁹ G.H. Chen and M.E. Raikh, Phys. Rev. B 60, 4826 (1999).

²⁰ R J. E lliott, Phys. Rev. 96, 266 (1954); M J. D'yakonov and V J. Perel, Fiz. T verd. Tela 13, 3581 (1971) [Sov. Phys. Solid State 13, 3023 (1971)]; P. Boguslawski, Solid State C om m un. 33, 389 (1980); M M. G lazov and E J. Ivchenko, JETP Letters 75, 403-405 (2002).

²¹ J.F.Janak, Phys. Rev. 178, 1416 (1969).

S.Yarlagadda and G.F.Giuliani, Phys.Rev.B 40, 5432 (1989).

 $^{^{23}}$ C S.T ing, T K .Lee, and J.J.Quinn, Phys.Rev.Lett.34,

- 870 (1975).
- ²⁴ A. V. Chubukov and D. L. Maslov, Phys. Rev. B 68, 155113 (2003).
- Y. Zhang and S. Das Sarma, Phys. Rev. B 70, 035104 (2004).
- ²⁶ K.M orawetz, Europhys. Lett. 67,77 (2004).
- ²⁷ P.Bloom, Phys.Rev.B 12, 125 (1975).
- 28 R. Jalabert and S. Das Sarma, Phys. Rev. B 40, 9723 (1989).
- ²⁹ G. Burkard, D. Loss, and E.V. Sukhorukov, Phys. Rev. B 61, R16303 (2000).
- ³⁰ V M .G alitski and S.D as Sarm a, Phys. Rev. B 70, 035111 (2004).
- 31 Y A .Bychkov and E J.Rashba, J.Phys.C 17,6039 (1984).
- 32 N ote that the expressions given in Refs. and 3 only agree for the dom inant logarithm $\log{(\ =\! E_F)}$, while the rest of O (1) di er.
- The param ater $r_s = r_s$ 2 is also used in the literature.
- 34 T.Ando, A.B.Fow ler, and F.Stern, Rev.M. od.Phys.54,

- 437 (1982).
- 35 Y. Sato, T. Kita, S. Gozu, and S. Yam ada, J. Appl. Phys. 89, 8017 (2001).
- For a detailed study of the C oulom b scattering of two electrons in a 2D EG, see D. S. Saraga, B. L. Altshuler, D. Loss, and R. M. W estervelt, Phys. Rev. Lett, 92, 246803 (2004); Phys. Rev. B 71, 045338 (2005).
- ³⁷ E.J.Rashba, Phys. Rev. B 68, 241315 (R) (2003).
- ³⁸ F.Stem, Phys. Rev. Lett. 18, 546 (1967).
- M. Abram ow itz and IA. Stegun, Handbook of mathematical functions (Dover Publications, New-York, 1965).
- ⁴⁰ JB. M iller, D M. Zum buhl, C M. M arcus, Y B. Lyanda-Geller, D. Goldhaber-Gordon, K. Campman, and A.C. Gossard, Phys. Rev. Lett. 90, 076807 (2003).
- $^{41}\,$ S.G angadharaiah, D. L.M aslov, cond-m at/0505534.
- ⁴² A. Shekhter, M. Khodas, and A. M. Finkel'stein, Phys. Rev. B 71, 165329 (2005).
- $^{\rm 43}$ M .P letyukhov and V .G ritsev, cond-m at/0506227.